Low Vce (sat) Transistor (DC-DC converter) (-20V, -10A)

Features

- 1) Low VCE(eas). (Typ.-0.16V at Ic/Is=-4V/-50mA)
- 2) High current capacity. (Ic=-10A/DC, -15A/10ms pulse)
- 3) Complements the 2SC5001.

●Packaging specifications and hre

Туре	28A1834
Package	CPT3
hre	RS
Code	TL
Basic ordering unit (pieces)	2500

●Absolute maximum ratings (Ta=25℃)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vcao	-30	V
Collector-emitter voltage	VCEO	20	V
Emitter-base voltage	VEBO	-6	V
Collector current	lc	-10	A
	ICP	-15	A *
Base current	l _B	-2	Α
Collector power dissipation		1	W
	Pc	10	W (Tc=25℃)
Junction temperature	Tj	150	b
Storage temperature	Tstg	−55~150	r

^{*} Sigle pulse Pw=10ms

●Electrical characteristics (Ta=25℃)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	BVcso	-30	I —	_	V	lc=-50 μA	
Collector-emitter breakdown voltage	BVceo	-20	_	_	v	lc=−1mA	
Emitter-base breakdown voltage	BVEBO	-в		_	V	Iε=-50 μA	
Collector cutoff current	Iceo		-	-1	μA	Vc8=-20V	
Emitter cutoff current	IEBO		_	-1	μA	VEB=-5V	
Collector-emitter saturation voltage	VCE(set)		-0.16	-0.25	v	Ic/Is=-4A/-0.05A	*
Base-emitter saturation voltage	VBE(set)	_	-0.9	-1.2	ν	Ic/Is=-4A/-0.05A	*
DC current transfer ratio	hrei	120		560	_	Vc=-2V, lc=-0.5A	*
DC current transfer ratio	hre2	82	—		_	Vc==-2V, lc=-4A	*
Transition frequency	fr	_	150		MHz	Vc=-5V, I=1.5A, f=50MHz	
Output capacitance	Cob		220		ρF	Vcs=-10V, IE=0A, f=1MHz	

Measured using pulse current.

(96-106-B217)

Low Vce (sat) Transistor (Strobe flash) (20V, 10A) 2SC5001

●Features

- 1) Low Vce(eet). (Typ. 0.13V at lc/le=4A/50mA)
- 2) High current capacity, (Ic=10A/DC, 15A/10ms pulse)
- ,3) Complements the 2SA1834.

Packaging specifications and hre

Туре	2SC5001
Package	СРТЗ
hre	QR
Code	TL
Basic ordering unit (pieces)	2500

●Absolute maximum ratings (Ta=25℃)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vceo	30	V
Collector-emitter voltage	Vceo	20	V
Emitter-base voltage	VEBO	6	V
Collector current	lc	10	A
	ICP	15	A *
Base current	le le	2	Α
Collector power dissipation	-	1	W
	Pc	10	W(Tc=25℃)
Junction temperature	Ti	150	2
Storage temperature	Tstg	−55~150	Υ

^{*} Sigle pulse Pw=10ms

●Electrical characteristics (Ta=25℃)

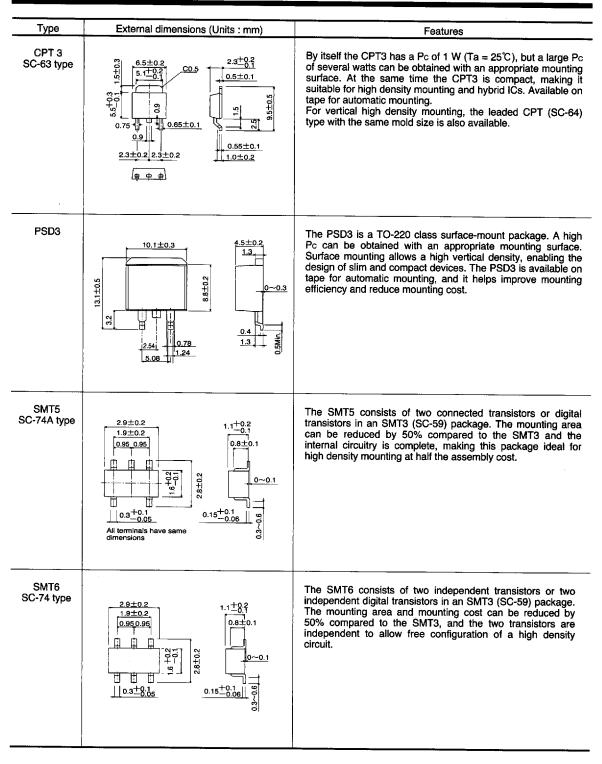
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BVcso	30	_	_	V	Ic=50 μA
Collector-emitter breakdown voltage	BVceo	20			V	lc=1mA
Emitter-base breakdown voltage	BVEBO	- 6		_	V	IE=50 μ A
Collector cutoff current	Iceo	_		1	μA	Vcs=20V
Emitter cutoff current	leno	—	_	1	μΑ	Ves=5V
Collector emitter saturation voltage	VCE(set)	_	0.13	0.25	٧	Ic/Is=4A/0.05A
Base-emitter saturation voltage	VBE(eat)	_	_	1.2	V	Ic/Is=4A/0.05A
C current transfer ratio	heer	120	_	390	_	Vce/lc=5V/0.1A
DC current transfer ratio	hre2	82	_	_		Vce=2V , Ic=4A
Transition frequency	fr	_	150	_	MHz	Vce=5V , le=-1.5A , f=50MHz
Output capacitance	Cob	_	220	_	pF	Vcs=10V, IE=0A, f=1MHz

Packages

ROHM has been manufacturing transistors since 1975. In the development of products, we constantly strive to anticipate the needs of our customers. Regarding packages, the demands of the market for compactness, low power consumption, low power dissipation and automatic mounting support are becoming ever greater, and we are strengthening our product development system to meet these needs.

●Types and features of surface-mount packages

Туре	External dimensions (Units : mm)	Features
EMT3 SC-75A type	0.2±0.1 0.2±0.1 0.2±0.1 0.2±0.1 0.2±0.1 0.1±0.55 0.1±0.55 0.1±0.55 0.1±0.55 0.1±0.55 0.1±0.55	A more compact version of the UMT3 (SC-70), the EMT3 is the world's smallest transistor with a mold size of 1.6 × 0.8 mm. The mounting area is approximately 60% of the UMT3 and 30% of the SMT3, making it ideal for ultra-high density mounting. Mounting is possible with the same type of automatic mounting machine as the UMT3.
UMT3 SC-70 type	2.0±0.2 1,3±0.1 0,65 0,65 0,2 0,7±0.1 0,3±0.1 0,3±0.1 0,15±0.05 0,15±0.05	The UMT3 is a smaller version of the SMT3 (SC-59). The mounting area is approximately 60% of the SMT3, making it optimum for high density mounting. The taping size is the same as the SMT3, allowing use of conventional automatic mounting machines. Electrical characteristics and reliability are the same as the SMT3.
SMT3 SC-59 type	2.9±0.2 1.9±0.2 0.950.95 0.8±0.1 0.0000 0.000 0.000 0.000 0.000 0.000 0.000 0.000 0.000 0.00000 0.00000 0.00000 0.00000 0.00000 0.000000 0.00000 0.00000 0.00000 0.00000 0.00000 0.000000 0.000000 0.000000 0.000000 0.00000000	The SMT3 is a compact package suitable for small electronic devices and hybrid IC applications. With proven performance, this is one of the most basic small packages. With the exception of Pc (collector power dissipation), electrical characteristics are similar to leaded packages. Reliability is on the same level as the TO-92.
MPT3 SC-62 type	4.6 ^{+0.2} 1.8±0.1 1.5±0.1 0.4±0.1 0.4±0.1 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1	By itself the MPT3 has a Pc of 0.5 W (Ta = 25°C), but when used on a 40 × 40 × 0.7 mm ceramic board, Pc = 2 W (Tc = 25°C), allowing high power to be obtained with a small package. The flat package makes it suitable for applications requiring compactness such as hybrid ICs. Available on tape for automatic mounting.



Туре	External dimensions (Units : mm)	Features
UMT5 SC-88A type	2.0±0.2 1,3±0.1 0,85 0,85 0,7 0,85 0,95 0,7 0,15±0.05 All terminals have same dimensions	The UMT5 consists of two connected transistors or digital transistors in a UMT3 (SC-70) package. The mounting area can be reduced by 50% compared to the UMT3 and the internal circuitry is completed, making this package ideal for high density mounting at half the assembly cost.
UMT6 SC-88 type	2.0±0.2 1,3±0.1 0.65 0.65 0.7 0.7 0.7 0.7 0.7 0.7 0.7 0.7	The UMT6 consists of two independent transistors or two independent digital transistors in a UMT (SC-70) package. The mounting area and mounting cost can be reduced by 50% compared to the UMT3, and the two transistors are independent to allow free configuration of a high density circuit.

 Types and features of leaded package 	Types	and featu	res of lead	ded packages
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Туре	External dimensions (Units : mm)	Features
SPT (SC-72 type)	2±0.2 0.45+0.15 0.45+0.15 0.5 0.45±0.05	The SPT is a smaller version of the conventional TO-92 type. The body size (3×4×2 mm³) has been reduced to 1/4 that of the TO-92 (5×5×4 mm³). The SPT is available on tape for automatic insertion, and less space is occupied on the printed circuit board than the TO-92. Reliability is the same as the TO-92.
FTR	0.65±0.1	SIL type with a height of 3.4 mm and a lead pitch of 2.54 mm.
FTL	0.65Max 2.542.54 2.11 0.45±0.1	The FTL is a radial taping version of the highly popular FTR. This enables automatic high-density mounting with a radial insertion machine.
ATR (SC-71 type)	0.65Max. 0.45±0.1	SC-71type with a height of 4.4 mm and a Pc=1W type.

Туре	External dimensions (Units : mm)	Features
ATV	0.65Max 2.5±0.2 0.65Max 2.5±0.1 0.5±0.1 0.5±0.1 0.45±0.1	The ATV is a radial taping version of the highly popular ATR. This enables automatic high-density mounting with a radial insertion machine.
TO-92 (SC-43 type)	4.8±0.2 3.7±0.2 0.5±0.1 2.5±0.1 5 0.45±0.1 2.3	The SC-43 is for general purpose small signals.
TO-126FP	7.8±0.2 Front ±3.3 Reer ≠3.18 Feer ≠3.18 Co.7 Co.7 Co.7 Co.7 Co.7 Co.7 Co.7 Co.7	The TO-126FP is an isolation type package based on a TO-126 full mold. In addition to the features of the TO-126, molded heat sink fins allow easy isolation of the heat sink.
TO-220FP (SC-67 type)	70+021 70+03 7	The TO-220FP is an isolation type package based on a TO-220 full mold. In addition to the features of the TO-126 and TO-220, molded heat sink fins allow easy isolation of the heat sink.

Туре	External dimensions (Units : mm)	Features
TO-220FN	10.0+0.3 4.5+0.3 4.5+0.3 2.8+0.2 2.	The TO-220FN features the same performance as the TO-220FP with approximately 2 mm less height, allowing the design of slimmer devices. Furthermore, the elimination of support pins in the fin (collector electrode) solves short-circuiting problems with neighboring components and the chassis. To make the height to the installation hole the same as the TO-220FP, it can be replaced as is from the TO-220FP.